







LMK6C, LMK6D, LMK6H, LMK6P SNAS826E - APRIL 2022 - REVISED APRIL 2024

LMK6x Low Jitter, High-Performance BAW Oscillator

1 Features

- High-performance differential and single-ended output Oscillator, supporting any fixed frequency within the below range:
 - LMK6D: 1MHz to 400MHz, LVDS output
 - LMK6H: 1MHz to 400MHz, HCSL output
 - LMK6P: 1MHz to 400MHz, LVPECL output
 - LMK6C: 1MHz to 200MHz, LVCMOS output
- Ultra-low jitter:
 - LMK6D/LMK6H/LMK6P: 100fs typical / 125fs maximum RMS jitter at 156.25MHz (12kHz to 20MHz)
 - LMK6C: 350fs typical / 500fs maximum RMS jitter at 100MHz (12kHz to 20MHz)
 - LMK6H: PCIe Gen 1 to Gen 6 compliant
- ±25ppm total frequency stability inclusive of 10 years aging and all other factors
- Smallest industry standard DLE and DLF packages
- Support extended industrial temperature grade:
 - LMK6P/LMK6D/LMK6H: –40°C to 85°C
 - LMK6C: –40°C to 105°C
- Integrated LDO for robust supply noise immunity:
 - 72dBc PSRR at 500kHz ripple
- Start-up time: < 5ms
- Standard frequencies:
 - LVCMOS (MHz): 1, 2.04, 4, 8.192, 10, 12, 12.288, 16, 19.2, 20, 23.5, 24, 24.57, 25, 25.6, 26, 26.21, 27, 28.12, 32.768, 33.333, 40, 48, 49.15, 50, 54, 60, 65.53, 66, 74.25, 76.8, 80, 100, 108, 125, 133.330 and 156.25
 - Differential (MHz): 25, 26, 32.5, 50, 51.84, 54, 65, 76.8, 80, 100, 108, 122.88, 125, 133.330, 148.35, 148.5, 150, 155.52, 156.25, 161.1328125, 200, 312.5, and 400
- Device can support any frequency between 1MHz to 400MHz. Contact TI representative for any frequency and samples needed

2 Applications

- 56G/112G PAM4 clocking
- 100G/200G/400G/800G Optical Transport Network and Coherent Optics
- Network equipment, switches, routers, line cards, SAN, data centers and baseband units (BBU)
- PCIe Gen 1 to Gen 6 compliant reference clock
- Industrial applications
- Test and measurement
- ASIC, FPGA, MCU reference clocking
- High-performance crystal oscillator replacement

3 Description

Texas Instruments' Bulk-Acoustic Wave (BAW) is a micro-resonator technology that enables integration of high-precision BAW resonator directly into packages with ultra-low jitter clock circuitry. BAW is fully designed and manufactured at TI factories like other silicon-based fabrication processes.

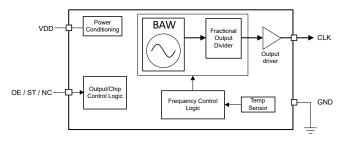
The LMK6x device is an ultra-low jitter, fixedfrequency oscillator which incorporates the BAW as the resonator source. The device is factoryprogrammed per specific operation mode, including frequency, voltage, output type, and function pin. With a high-performance fractional frequency divider, the LMK6x is capable of producing any frequency within the specified range providing a single device family for all frequency needs.

The high-performance clocking, mechanical stability, flexibility, and small package options for this device are designed for reference and core clocks in highspeed SERDES used in telecommunications, data and enterprise network, and industrial applications.

Package Information

PART NUMBER	OUTPUT TYPE	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾		
LMK6C	LVCMOS	VSON (DLE-4)	3.2mm × 2.5mm		
LMK6C	LVCIVIOS	VSON (DLF-4)	2.5mm × 2mm		
LMK6D LMK6H LMK6P	LVDS,	VSON (DLE-6)	3.2mm × 2.5mm		
LMK6D LMK6H LMK6P	HCSL, LVPECL	VSON (DLF-6)	2.5mm × 2mm		

- For all available packages, see Section 12.
- The package size (length × width) is a nominal value and includes pins, where applicable.



LMK6C Simplified Block Diagram



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4 Device Ordering Information

Use Figure 4-1 and Figure 4-2 to understand the device nomenclature of the LMK6x orderable options.

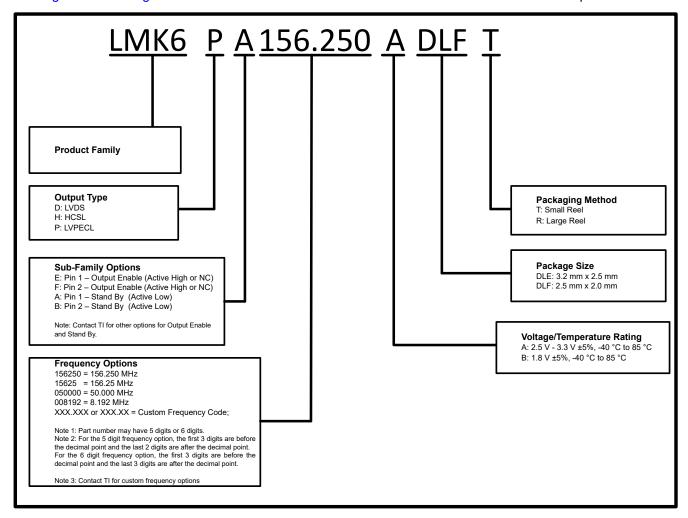


Figure 4-1. Part Number Guide: LMK6D, LMK6H, and LMK6P



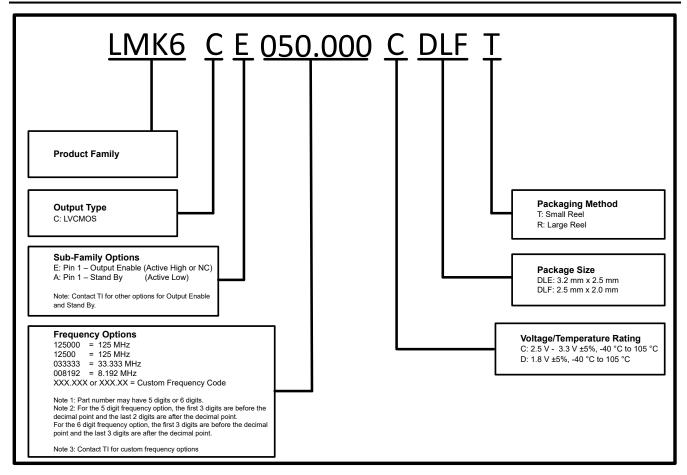


Figure 4-2. Part Number Guide: LMK6C



5 Pin Configuration and Functions

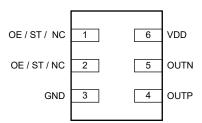


Figure 5-1. LMK6P, LMK6D, or LMK6H 6-Pin VSON (Top View)

Table 5-1. LMK6P, LMK6D, or LMK6H Pin Functions

PIN		Type ⁽¹⁾	DESCRIPTION	
NAME	DLE/DLF	туре	DESCRIPTION	
OE / ST / NC	1	I / NC	Output Enable (OE) or Standby (ST) pin or No Connect (NC). See Table 8-1 for more details.	
OE / ST / NC	2	NC / I	NC / I Output Enable (OE) or Standby (ST) pin or No Connect (NC). See Tabl for more details.	
GND	3	G	Device ground	
OUTP	4	0	Positive differential output clock	
OUTN	5	0	Negative differential output clock	
VDD	6	Р	Device power supply	

(1) I = Input, O = Output, I/O = Input or Output, G = Ground, P = Power, NC = No Connect (can be left floating).

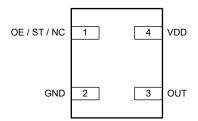


Figure 5-2. LMK6C 4-Pin VSON (Top View)

Table 5-2. LMK6C Pin Functions

PIN		Type ⁽¹⁾	DESCRIPTION
NAME	DLE/DLF DESCRIPTION		DESCRIPTION
OE / ST / NC	1	I / NC	Output Enable (OE) or Standby (ST) pin or No Connect (NC). See Table 8-2 for more details.
GND	2	G	Device ground
OUT	3	0	LVCMOS output clock
VDD	4	Р	Device power supply

(1) I = Input, O = Output, I/O = Input or Output, G = Ground, P = Power, NC = No Connect (can be left floating).



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
VDD	Device Supply Voltage ⁽²⁾	-0.3	3.63	V
VDD	Device Supply Voltage ⁽³⁾	-0.3	1.98	V
EN	Logic Input Voltage	-0.3	VDD + 0.3	V
OUTP, OUTN	Clock Output Voltage ⁽⁴⁾	-0.3	VDD + 0.3	V
OUT	Clock Output Voltage ⁽⁵⁾	-0.3	VDD + 0.3	V
TJ	Junction Temperature		125	°C
T _{STG}	Storage Temperature		150	°C

⁽¹⁾ Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

- (2) For all devices with Recommended Operating Voltage of 2.5 V +/- 5% and 3.3 V +/- 5%
- (3) For all devices with Recommended Operating Voltage of 1.8 V +/- 5%
- (4) For all differential outputs LMK6D, LMK6H, and LMK6P.
- (5) For single ended outputs LMK6C.

6.2 ESD Ratings

			VALUE	UNIT
V	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/ JEDEC JS-001, all pins ⁽¹⁾	±2000	V
V _(ESD)	Electrostatic discriarge	Charged device model (CDM), per JEDEC JS-002, all pins ⁽²⁾	±500	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Environmental Compliance

		VALUE	UNIT
Mechanical Shock Resistance	MIL-STD-883F, Method 2002, Condition A	1500	g
Mechanical Vibration Resistance	MIL-STD-883F, Method 2026, Condition C	10	g
	MIL-STD-883F, Method 2007, Condition A	20	g
Moisture Sensitivity Level (MSL)		MSL1	

6.4 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
VDD	Device Supply Voltage ⁽¹⁾	1.7	1.8	1.9	V
	Device Supply Voltage ⁽²⁾	2.37	2.5, 3.3	3.5	V
_	Ambient temperature ⁽³⁾	-40		85	°C
T _A	Ambient temperature ⁽⁴⁾	-40		105	°C
TJ	Junction temperature			125	°C
t _{RAMP}	VDD power-up ramp time ⁽¹⁾ (2)	0.1		100	ms

- (1) For all devices with Recommended Operating Voltage of 1.8V +/- 5%
- (2) For all devices with Recommended Operating Voltage of 2.5V +/- 5% and 3.3V +/- 5%
- (3) For all differential outputs LMK6D, LMK6H and LMK6P.
- (4) For single-ended output LMK6C.



6.5 Thermal Information

THERMAL METRIC(1)		LMK	LMK6D/H/P		
		DLE (VSON)	DLF (VSON)	UNIT	
		6 PINS	6 PINS		
R _{θJA}	Junction-to-ambient thermal resistance	101.2	107.9	°C/W	
R _{θJC(top)}	Junction-to-case (top) thermal resistance	58.6	70.1	°C/W	
R _{θJB}	Junction-to-board thermal resistance	31.3	39.4	°C/W	
Ψ_{JT}	Junction-to-top characterization parameter	2.7	2.3	°C/W	
Ψ_{JB}	Junction-to-board characterization parameter	31.1	39.2	°C/W	

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.6 Thermal Information

		LM	LMK6C			
	THERMAL METRIC(1)	DLE (VSON)	DLF (VSON)	UNIT		
		4 PINS	4 PINS			
R _{0JA}	Junction-to-ambient thermal resistance	124.8	128.1	°C/W		
R _{0JC(top)}	Junction-to-case (top) thermal resistance	61.2	73.2	°C/W		
$R_{\theta JB}$	Junction-to-board thermal resistance	42.5	39.8	°C/W		
Ψ_{JT}	Junction-to-top characterization parameter	2.8	2.4	°C/W		
Ψ_{JB}	Junction-to-board characterization parameter	42.3	39.5	°C/W		

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.



6.7 Electrical Characteristics

over Recommended Operating Conditions, Typical Temp = 25°C, Frequency output = 156.25 MHz, VDD = 3.3 V, LVCMOS Output Capacitor load = 2.2 pF (unless otherwise specified)⁽⁷⁾

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Current	Consumption Characteristics					
		100 MHz		65	82	mA
	Device Power Consumption	156.25 MHz		69	87	mA
	(LVPECL,VDD = 2.5 V/3.3 V, Excluding	200 MHz		67	85	mA
	load current)	312.5 MHz		76	95	mA
		400 MHz		88	108	mA
		100 MHz		61	79	mA
	Device Power Consumption	156.25 MHz		66	83	mA
	(LVPECL,VDD = 1.8 V, Excluding load	200 MHz		64	82	mA
	current)	312.5 MHz		73	91	mA
		400 MHz		84	104	mA
		100 MHz		65	82 87 85 83 108 79 8 83 82 82 8 91 104 8 82 8 87 7 86 8 88 7 97 8 88 8 7 97 8 8 8 8 8 7 97 8 8 8 8	mA
		156.25 MHz		69	87	mA
	Device Power Consumption (HCSL,VDD = 2.5 V/3.3 V, Excluding load current)	200 MHz		67	86	mA
	2.0 V/0.0 V, Exchang load currently	312.5 MHz		76	96	mA
		400 MHz	65 69 67 76 88 88 61 66 64 73 84 65 69 67 76 88 58 62 60 69 77 54 58 56 65 76 52 56 65 76 52 56 65 65 65	108	mA	
	Device Power Consumption (HCSL,VDD = 1.8 V, Excluding load current)	100 MHz		58	75	mA
		156.25 MHz		62	80	mA
		200 MHz		60	78	mΑ
D	1.5 V, Excidentify load durinity	312.5 MHz		69	88	mΑ
		400 MHz		77	97	mA
		100 MHz		54	71	mA
		156.25 MHz		58	75	mA
	Device Power Consumption (LVDS,VDD = 2.5 V/3.3 V, Excluding load current)	200 MHz		56	74	mA
	= 2.5 V/5.5 V, Excluding load currenty	312.5 MHz		65 82 69 87 67 85 76 95 88 108 61 79 66 83 64 82 73 91 84 104 65 82 69 87 67 86 76 96 88 108 58 75 62 80 60 78 69 88 77 97 54 71 58 75 56 74 65 84 76 96 52 68 56 72 54 71 63 80 74 92 45 62 55 71 61 77 44 59 50 65 56 72 6 13 48 67 49 66	mA	
		400 MHz		76	96	mA
		100 MHz		52	68	mA
		156.25 MHz		56	72	mA
	Device Power Consumption (LVDS,VDD = 1.8 V, Excluding load current)	200 MHz		54	71	mA
	- 1.5 V, Exciduing load current)	312.5 MHz		65 8 69 8 67 8 76 9 88 10 61 7 66 8 64 8 73 9 84 10 65 8 69 8 67 8 76 9 88 10 58 7 62 8 60 7 69 8 77 9 54 7 58 7 56 7 65 8 76 9 88 10 58 7 62 8 60 7 69 8 77 9 54 7 58 7 56 7 65 8 76 9 87 7 98 8 77 9 54 7 58 7 56 7 65 8 76 9 88 7 69 8 77 9 54 7 58 7 69 8 70 9 69 8 71 9 54 7 58 7 65 8 76 9 65 8 76 9 69 8 77 9 54 7 58 7 65 7 65 8 76 9 65 8 76 9 65 7 65 8 76 9 65 8 76 9 66 7 67 8 76 9 68 7 69 8 77 9 54 7 58 7 65 7 65 8 76 9 65 7 65 7 65 7 65 7 66 7 67 7 68 7 69 7 69 8 70 9 69 8 70 9 60 7 60	80	mA
DD-STBY [400 MHz		74	92	mA
	Device Power	100 MHz		45	62	mA
	Consumption (LVCMOS,VDD = 2.5 V /	156.25 MHz		55	71	mA
	3.3 V, with load)	200 MHz		61	77	mA
	Device Power	100 MHz		44	59	mA
	Consumption (LVCMOS,VDD = 1.8 V,	156.25 MHz		50	65	mA
	with load)	200 MHz		56	72	mA
D-STBY	Device Stand By current	ST (Stand By) = GND		6	13	mA
		OE = GND, LVPECL mode, VDD = 3.3 V		48	67	mA
	Device current with output disabled (100	OE = GND, HCSL mode, VDD = 3.3 V		49	67	mA
DD-PD	MHz)	OE = GND, LVDS mode, VDD = 3.3 V		49	66	mA
DD-STBY		OE = GND, LVCMOS mode, VDD = 3.3 V		40	56	mA



over Recommended Operating Conditions, Typical Temp = 25° C, Frequency output = 156.25 MHz, VDD = 3.3 V, LVCMOS Output Capacitor load = 2.2 pF (unless otherwise specified)⁽⁷⁾

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
F _{out}	Output Frequency		1		400	MHz
		AC coupled, VDD = 3.3V	525	645	765	mV
		AC coupled, VDD = 2.5V	450	555	660	mV
V _{OD}	Output Voltage Swing (V _{OH} - V _{OL})	AC coupled, VDD = 1.8 V	280	375	470	mV
		DC coupled, VDD = 2.5 V/ 3.3 V ⁽¹⁾	650	800	950	mV
		DC coupled, VDD = 1.8 V ⁽¹⁾	450	600	750	mV
$V_{OD,DIFF}$	Differential Output peak-peak swing			2× V _{OD}		V_{pp}
		VDD = 3.3 V ⁽¹⁾	1.5	1.6	1.7	V
Vos	Output Common-Mode Voltage	VDD = 2.5 V ⁽¹⁾	0.825	0.9	0.975	V
		VDD = 1.8 V ⁽¹⁾	0.45	0.5	0.55	V
t _R /t _F	Output Rise/Fall Time	20% to 80% of V _{OD,DIFF} , VDD = 2.5 V/ 3.3 V		120	200	ps
		20% to 80% of V _{OD,DIFF} , VDD = 1.8 V		120	200	ps
ODC	Output Duty Cycle	VDD = 2.5 V/ 3.3V, measured between 50% points on the waveform	45	50	55	%
ODC	Output Duty Cycle	VDD = 1.8 V, measured between 50% points on the waveform	45	50	55	%
LVDS Ou	tput Characteristics					
F _{out}	Output Frequency		1		400	MHz
V_{OD}	Output Voltage Swing (V _{OH} - V _{OL})	Under LVDS Load condition	250	350	450	mV
$V_{OD,DIFF}$	Differential Output peak-peak swing			$2 \times V_{OD} $		V_{pp}
V _{OS}	Output Common Mode Voltage	VDD = 2.5V/3.3 V	1.025	1.2	1.375	V
		VDD = 1.8 V	0.80	0.9	1.0	V
t _R /t _F	Output Rise/Fall Time	20% to 80% of V _{OD,DIFF} , VDD = 2.5V/3.3 V		150	250	ps
		20% to 80% of V _{OD,DIFF} , VDD = 1.8V		150	250	ps
ODC	Output Duty Cycle	VDD = 2.5 V/3.3 V, measured between 50% points on the waveform	45	50	55	%
ODC	Output Daily Gyole	VDD = 1.8V, measured between 50% points on the waveform	45	50	55	%
HCSL Ou	tput characteristics					
F _{out}	Output Frequency		1		400	MHz
V_{OH}	Output High Voltage	DC coupled, 50 ohms to ground, VDD = 2.5 V/ 3.3 V	650	750	850	mV
∨ОН	Output Figit Voltage	DC coupled, 50 ohms to ground, VDD = 1.8 V	460	560	660	mV
V-	Output Low Voltage	DC coupled, 50 ohms to ground, VDD = 2.5 V/ 3.3 V	-150	0	150	mV
V _{OL}	Output Low Voltage	DC coupled, 50 ohms to ground, VDD = 1.8 V	-150	0	150	mV
$V_{OD,DIFF}$	Differential Output peak-peak swing			2× V _{O H -} V _{OL}		V
V	Absolute Crossing Point Voltage	VDD = 3.3 V / 2.5 V, f _{out} = 100 MHz	0.2	0.35	0.50	V_{pp}
V _{cross}	, associate Grossing Fourit voltage	VDD = 1.8 V, f _{out} = 100 MHz	0.15	0.275	0.40	V_{pp}
V _{cross-} delta	Absolute Crossing Point Voltage variation	VDD = 3.3 V / 2.5 V / 1.8 V, f _{out} = 100 MHz		0.14		V
dV/dt	Output Slew Rate	50 ohms to ground; DC coupled load; measured slew rate in +/-150mV from Center.	2		12	V/ns



over Recommended Operating Conditions, Typical Temp = 25°C, Frequency output = 156.25 MHz, VDD = 3.3 V, LVCMOS Output Capacitor load = 2.2 pF (unless otherwise specified)⁽⁷⁾

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
∆dV/dt	Output Slew Rate variation				20	%
ODC	Output Duty Cycle		45	50	55	%
LVCMOS	Output Characteristics			,	"	
F _{out}	Output Frequency		1		200	MHz
		I _{OL} = 3.6 mA, VDD = 1.8 V			0.36	V
V_{OL}	Output Low Voltage	I _{OL} = 5.0 mA, VDD = 2.5 V			0.5	V
		I _{OL} = 6.6 mA, VDD = 3.3 V			0.66	V
		I _{OH} = 3.6 mA, VDD = 1.8 V	1.44	,		V
V _{OH}	Output High Voltage	I _{OH} = 5.0 mA, VDD = 2.5 V	2			V
		I _{OH} = 6.6 mA, VDD = 3.3 V	2.64			V
t _R /t _F	Output Rise/Fall Time	20% to 80% of V _{OH} -V _{OL} , C _L = 2 pF		0.5	1	ns
ODC	Output Duty Cycle		45	50	55	%
R _{out}	Output Impedance	OE = HIGH	40	50	60	Ω
· ·out		Fout > 50 MHz ⁽³⁾			15	pF
CL	Maximum capacitive load	Fout < 50 MHz ⁽³⁾			30	pF
Function	Pin Input Characteristics (OE/ST pin)	1 out 3 ou miles			30	Pi
V _{IL}	Input Low Voltage				0.6	V
	Input High Voltage		1.3		0.0	V
V _{IH}	Input Low Current	OE = GND				
l _{IL}	<u>'</u>		-40		40	μΑ
I _{IH}	Input High Current	OE = VDD			40	μA
C _{IN}	Input Capacitance			2		pF
LVDS, H	CSL and LVPECL Frequency Tolerance					
F _T	Total Frequency Stability	Inclusive of: solder shift, initial tolerance, variation over -40°C to 85°C, variation over rated supply voltage range, and 10 year aging at 25°C.	-25		25	ppm
		Inclusive of: solder shift, initial tolerance, variation over -40°C to 85°C, variation over supply voltage range.	-20		20	ppm
LVCMOS	Frequency Tolerance				<u> </u>	
F _T	Total Frequency Stability	Inclusive of: solder shift, initial tolerance, variation over -40°C to 105°C, variation over rated supply voltage range, and 10 year aging at 25°C.	-25		25	ppm
•		Inclusive of: solder shift, initial tolerance, variation over -40°C to 105°C, variation over rated supply voltage range.	-20		20	ppm
Different	tial output PSRR Characteristics					
	Spur induced by 50 mV power supply	Sine wave at 50 kHz		–71		dBc
PSRR	ripple at 156.25 MHz output, VDD = 2.5	Sine wave at 100 kHz		–71		dBc
OINI	V/3.3 V, No power supply decoupling	Sine wave at 500 kHz		-72		dBc
	capacitor	Sine wave at 1 MHz		-70		dBc
		Sine wave at 50 kHz		-64		dBc
	Spur induced by 50 mV power supply	Sine wave at 100 kHz		-64		dBc
PSRR	ripple at 156.25 MHz output, VDD = 1.8 V, No power supply decoupling capacitor	Sine wave at 500 kHz		<u>–67</u>		dBc
. 0	v, No power supply decoupling capacitor	Sine wave at 1 MHz				dBc
		···-				



over Recommended Operating Conditions, Typical Temp = 25°C, Frequency output = 156.25 MHz, VDD = 3.3 V, LVCMOS Output Capacitor load = 2.2 pF (unless otherwise specified)⁽⁷⁾

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
		Sine wave at 50 kHz		-72		dBc
	Spur induced by 50 mV power supply	Sine wave at 100 kHz		-71		dBc
PSRR	ripple at 50MHz output, VDD = 2.5V/3.3 V, No power supply decoupling capacitor	Sine wave at 500 kHz		-70		dBc
	t, the period cappily accompaning capacitor	Sine wave at 1 MHz		-69		dBc
		Sine wave at 50 kHz		-50		dBc
	Spur induced by 50 mV power supply	Sine wave at 100 kHz		-50		dBc
PSRR	ripple at 50MHz output, VDD = 1.8V, No power supply decoupling capacitor	Sine wave at 500 kHz		-52		dBc
	have eached accepting each acces	Sine wave at 1 MHz		-55		dBc
PSRR	Jitter sensitivity to Power supply ripple;	100 kHz sine wave ripple, 3.3 V Supply ⁽²⁾		10		fs/mV
Power-Or	n Characteristics					
t _{START_UP}	Start-up Time	Time elapsed from 0.95 x VDD until output is enabled and output is within specification; Tested with a VDD supply ramp time of around 200 µs			5	ms
t _{OE-EN}	Output Enable Time	Time elapsed from OE = V _{IH} until output is enabled and output is within specification, F _{out} > 10 MHz			25	μs
t _{OE-DIS}	Output Disable Time	Time elapsed from OE = V _{IL} until output is disabled, F _{out} > 10 MHz			1	μs
LVPECL -	- Clock Output Jitter					
R_J	RMS Jitter (Integration BW: 12 kHz to 20 MHz)	F _{out} = 156.25 MHz		100	125	fs
PN _{1k}	Phase Noise at 1 kHz Offset			-95		dBc/Hz
PN _{10k}	Phase Noise at 10 kHz Offset			-127		dBc/Hz
PN _{100k}	Phase Noise at 100 kHz Offset	F _{out} = 156.25 MHz.		-146		dBc/Hz
PN _{1M}	Phase Noise at 1 MHz Offset			-156		dBc/Hz
PN _{10M}	Phase Noise at 10 MHz Offset			-158		dBc/Hz
R _J	RMS Jitter (Integration BW: 12 kHz to 20 MHz)	F _{out} = 312.5 MHz		100	125	fs
PN _{1k}	Phase Noise at 1 kHz Offset			-89		dBc/Hz
PN _{10k}	Phase Noise at 10 kHz Offset			-121		dBc/Hz
PN _{100k}	Phase Noise at 100 kHz Offset	F _{out} = 312.5 MHz.		-140		dBc/Hz
PN _{1M}	Phase Noise at 1 MHz Offset			-150		dBc/Hz
PN _{10M}	Phase Noise at 10 MHz Offset			-154		dBc/Hz
		F _{out} = 100 MHz		125	170	fs
		F _{out} = 125 MHz		100	125	fs
D	RMS Jitter (Integration BW: 12 kHz to 20	F _{out} = 155.52 MHz		100	125	fs
R_J	MHz)	F _{out} = 161.1328125 MHz		110	150	fs
		F _{out} = 200 MHz		120	150	fs
		F _{out} = 400 MHz		100	135	fs
RPeriodJITT ,RMS	RMS Period Jitter	F _{out} ≥ 25 MHz		1.7		ps
RJITT,PK- PK	Peak-peak Period Jitter	F _{out} ≥ 25 MHz		13		ps
LVDS - CI	lock Output Jitter					
R _J	RMS Jitter (Integration BW: 12 kHz to 20 MHz)	F _{out} = 156.25 MHz		100	125	fs



over Recommended Operating Conditions, Typical Temp = 25° C, Frequency output = 156.25 MHz, VDD = 3.3 V, LVCMOS Output Capacitor load = 2.2 pF (unless otherwise specified)⁽⁷⁾

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
PN _{1k}	Phase Noise at 1 kHz Offset			-95		dBc/Hz
PN _{10k}	Phase Noise at 10 kHz Offset			-128		dBc/Hz
PN _{100k}	Phase Noise at 100 kHz Offset	F _{out} = 156.25 MHz		-146		dBc/Hz
PN _{1M}	Phase Noise at 1 MHz Offset			-156		dBc/Hz
PN _{10M}	Phase Noise at 10 MHz Offset			-156.5		dBc/Hz
R _J	RMS Jitter (Integration BW: 12 kHz to 20 MHz)	F _{out} = 312.5 MHz		100	125	fs
PN _{1k}	Phase Noise at 1 kHz Offset			-89		dBc/Hz
PN _{10k}	Phase Noise at 10 kHz Offset			-122		dBc/Hz
PN _{100k}	Phase Noise at 100 kHz Offset	F _{out} = 312.5 MHz.		-139		dBc/Hz
PN _{1M}	Phase Noise at 1 MHz Offset			-150		dBc/Hz
PN _{10M}	Phase Noise at 10 MHz Offset			-153.5		dBc/Hz
		F _{out} = 100 MHz		140	170	fs
		F _{out} = 125 MHz		110	125	fs
П	RMS Jitter (Integration BW: 12 kHz to 20	F _{out} = 155.52 MHz		105	140	fs
R_J	MHz)	F _{out} = 161.1328125 MHz		125	160	fs
		F _{out} = 200 MHz		125	150	fs
		F _{out} = 400 MHz		100	135	fs
RPeriodJITT	RMS Period Jitter	F _{out} ≥ 25 MHz		1.6		ps
RJITT,PK- PK	Peak-peak Period Jitter	F _{out} ≥ 25 MHz		13		ps
HCSL - C	lock output jitter					
J _{PCle1-cc}	PCIe Gen 1 Common Clock jitter (jitter limit = 86 ps)		0.146		6.4	ps
J _{PCle1} - SRNS	PCIe Gen 1 SRNS jitter		0.447		6.99	ps
J _{PCle2-cc}	PCIe Gen 2 Common Clock jitter (jitter limit = 3 ps)		0.103		0.554	ps
J _{PCle2} - SRNS	PCIe Gen 2 SRNS jitter		0.135		0.56	ps
J _{PCle3-cc}	PCIe Gen 3 Common Clock jitter (jitter limit = 1 ps)		0.029		0.164	ps
J _{PCle3-} SRNS	PCIe Gen 3 SRNS jitter	- 400 MI	0.033		0.180	ps
J _{PCle4-cc}	PCIe Gen 4 Common Clock jitter (jitter limit = 500 fs)	F _{out} = 100 MHz	0.029		0.164	ps
J _{PCle4-} SRNS	PCIe Gen 4 SRNS jitter		0.033		0.180	ps
J _{PCle5-cc}	PCIe Gen 5 Common Clock jitter (jitter limit = 150 fs)		0.007		0.070	ps
J _{PCle5-} SRNS	PCIe Gen 5 SRNS jitter		0.007		0.074	ps
J _{PCle6-cc}	PCIe Gen 6 Common Clock jitter (jitter limit = 100 fs)		0.007		0.042	ps
J _{PCle6} - SRNS	PCIe Gen 6 SRNS jitter		0.009		0.052	ps
R _J	RMS Jitter (Integration BW: 12 kHz to 20 MHz)	F _{out} = 156.25 MHz		100	125	fs



over Recommended Operating Conditions, Typical Temp = 25°C, Frequency output = 156.25 MHz, VDD = 3.3 V, LVCMOS Output Capacitor load = 2.2 pF (unless otherwise specified)⁽⁷⁾

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
PN _{1k}	Phase Noise at 1 kHz Offset			-95		dBc/Hz
PN _{10k}	Phase Noise at 10 kHz Offset			-127		dBc/Hz
PN _{100k}	Phase Noise at 100 kHz Offset	F _{out} = 156.25 MHz.		-146		dBc/Hz
PN _{1M}	Phase Noise at 1 MHz Offset			-156		dBc/Hz
PN _{10M}	Phase Noise at 10 MHz Offset			-158		dBc/Hz
R_J	RMS Jitter (Integration BW: 12 kHz to 20 MHz)	F _{out} = 312.5 MHz		100	125	fs
PN _{1k}	Phase Noise at 1 kHz Offset			-89		dBc/Hz
PN _{10k}	Phase Noise at 10 kHz Offset			-121		dBc/Hz
PN _{100k}	Phase Noise at 100 kHz Offset	F _{out} = 312.5 MHz.		-140		dBc/Hz
PN _{1M}	Phase Noise at 1 MHz Offset			-150		dBc/Hz
PN _{10M}	Phase Noise at 10 MHz Offset			-154		dBc/Hz
		F _{out} = 100 MHz		125	170	fs
		F _{out} = 125 MHz		100	125	fs
_	RMS Jitter (Integration BW: 12 kHz to 20	F _{out} = 155.52 MHz		100	125	fs
R _J MHz)	, -	F _{out} = 161.1328125 MHz		110	150	fs
		F _{out} = 200 MHz		120	150	fs
		F _{out} = 400 MHz		100	135	fs
RPeriodJITT ,RMS	RMS Period Jitter	F _{out} ≥ 25 MHz		1.7		ps
RJITT,PK- PK	Peak-peak Period Jitter	F _{out} ≥ 25 MHz		13		ps
LVCMOS	- Clock Output Jitter				•	
R _J	RMS Jitter (Integration BW: 12 kHz to 20 MHz)	F _{out} = 156.25 MHz		0.25	0.5	ps
PN _{1k}	Phase Noise at 1 kHz Offset			-100		dBc/Hz
PN _{10k}	Phase Noise at 10 kHz Offset			-128		dBc/Hz
PN _{100k}	Phase Noise at 100 kHz Offset	F _{out} = 156.25 MHz		-143		dBc/Hz
PN _{1M}	Phase Noise at 1 MHz Offset			-150		dBc/Hz
PN _{10M}	Phase Noise at 10 MHz Offset			-152		dBc/Hz
		F _{out} = 24 MHz		0.25	0.5	ps
	RMS Jitter (Integration BW: 12 kHz to 5 MHz)	F _{out} = 25 MHz		0.25	0.5	ps
		F _{out} = 33.33 MHz		0.25	1	ps
		F _{out} = 40 MHz		0.5	1	ps
_		F _{out} = 50 MHz		0.4	1	ps
R_J		F _{out} = 66.66 MHz		0.5	1	ps
	RMS Jitter (Integration BW: 12 kHz to 20 MHz)	F _{out} = 74.25 MHz		0.3	0.5	ps
	1011 12)	F _{out} = 78 MHz		0.35	0.5	ps
		F _{out} = 100 MHz		0.35	0.5	ps
		F _{out} = 125 MHz		0.35	0.5	ps
RPeriodJITT ,RMS	RMS Period Jitter	F _{out} ≥ 25 MHz		1.5		ps
RJITT,PK- PK	Peak-peak Period Jitter	F _{out} ≥ 25 MHz		13		ps

⁽¹⁾ DC Load condition

⁽²⁾ Measured using TI LMK6x Evaluation Module;

⁽³⁾ Refer to Application Curves section for Rise time and fall time details for different capacitor load values.

(4) The Jitter specifications are based on design and characterization

6.8 Timing Diagrams

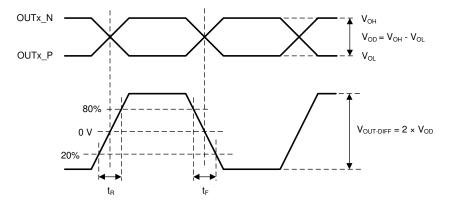


Figure 6-1. Differential Output Voltage and Rise/Fall Time

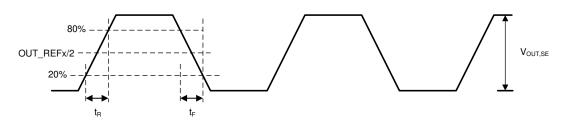
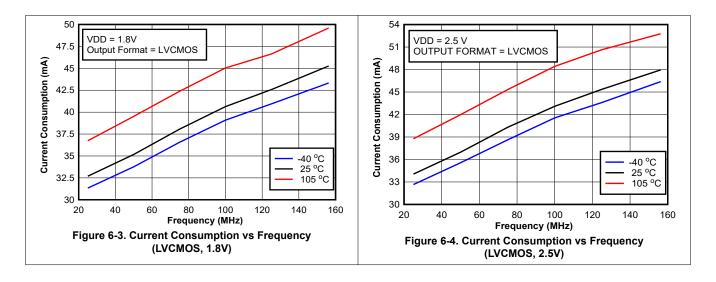
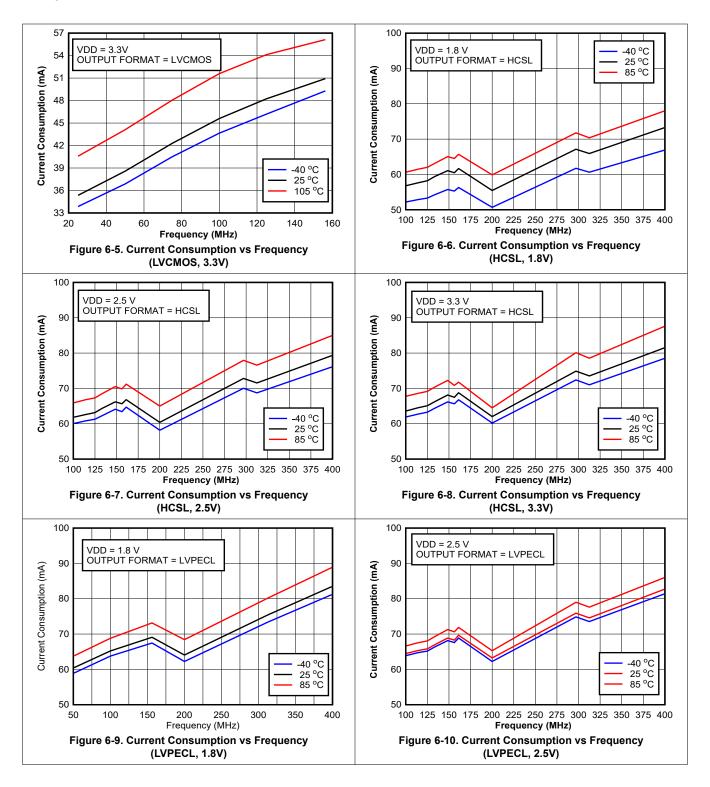


Figure 6-2. Single-Ended Output Voltage and Rise/Fall Time

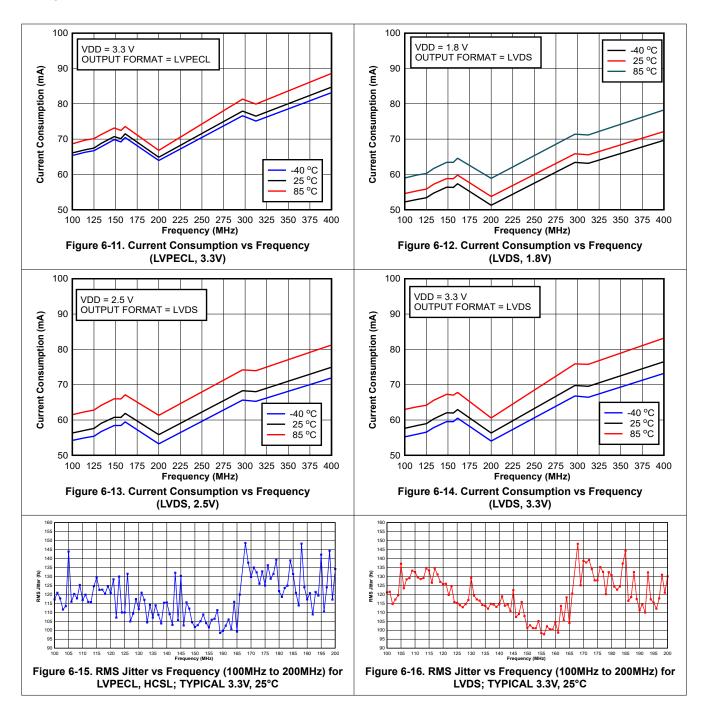
6.9 Typical Characteristics



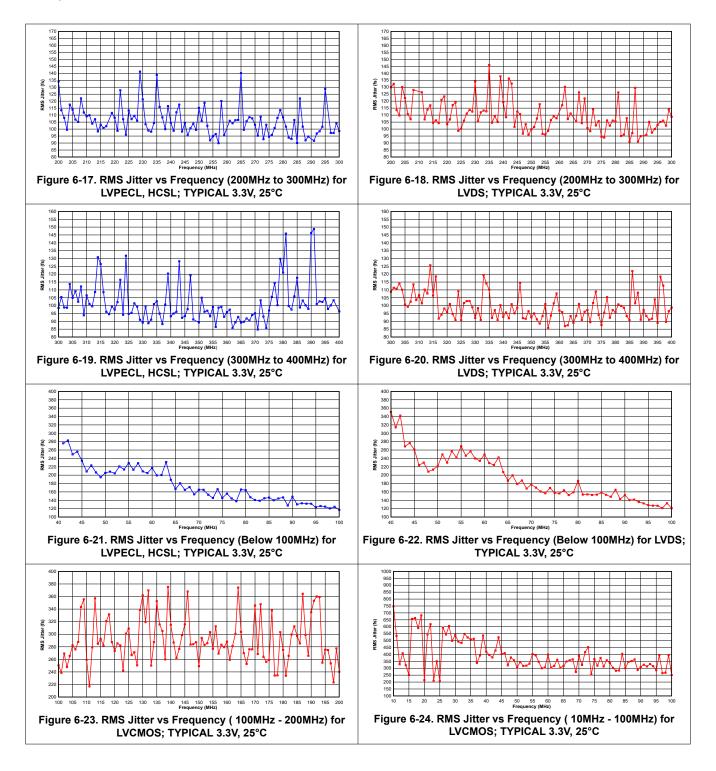




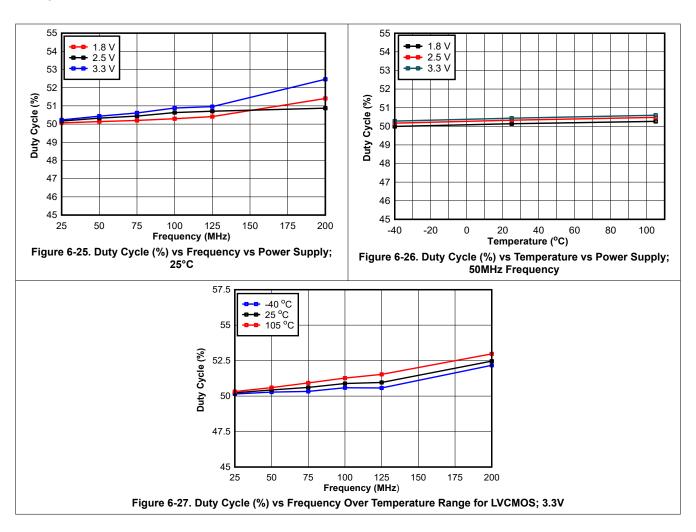














7 Parameter Measurement Information

7.1 Device Output Configurations

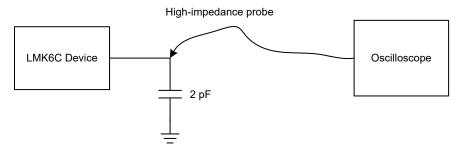


Figure 7-1. LMK6C Output Test Configuration

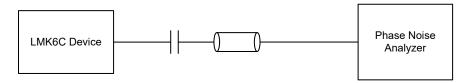


Figure 7-2. LMK6C Output Phase Noise Test Configuration

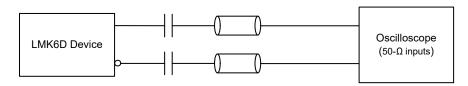


Figure 7-3. LMK6D Output Test Configuration

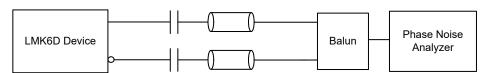


Figure 7-4. LMK6D Output Phase Noise Configuration

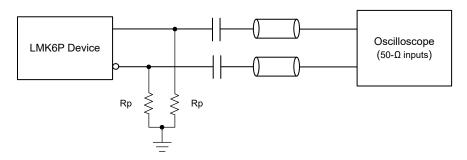


Figure 7-5. LMK6P Output Test Configuration



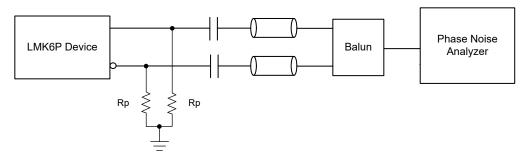


Figure 7-6. LMK6P Output Phase Noise Configuration

Table 7-1. LMK6P Output Test configuration and Phase Noise Configuration Rp Values

SUPPLY (V)	Rp (Ω)
3.3	207.5
2.5	112.5
1.8	83.3

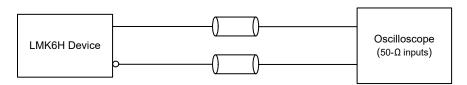


Figure 7-7. LMK6H Output Test Configuration

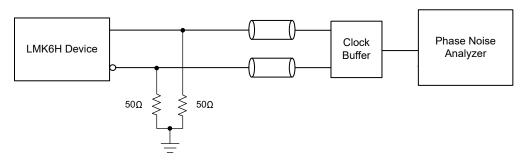


Figure 7-8. LMK6H Output Phase Noise Configuration

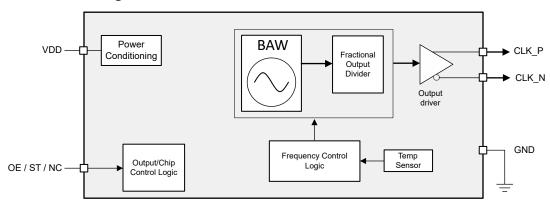


8 Detailed Description

8.1 Overview

The LMK6x is a fixed-frequency BAW based oscillator that can provide ultra-low jitter for both differential and single-ended output types.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Bulk Acoustic Wave (BAW)

TI's BAW resonator technology uses piezoelectric transduction to generate high-Q resonance at 2.5GHz. The resonator is defined by the quadrilateral area overlaid by top and bottom electrodes. Alternating high- and low-acoustic impedance layers form acoustic mirrors beneath the resonant body to prevent acoustic energy leakage into the substrate. Furthermore, these acoustic mirrors are also placed on top of the resonator stack to protect the device from contamination and minimize energy leakage into the package materials. This unique dual-Bragg acoustic resonator (DBAR) allows efficient excitation without the need of costly vacuum cavities around the resonator. As a result, Ti's BAW resonator is immune to frequency drift caused by adsorption of surface contaminants and can be directly placed in a non-hermetic plastic package with the oscillator IC in small standard oscillator footprints. Refer to BAW for more details on BAW technology.

8.3.2 Device Block-Level Description

The device contains a BAW oscillator, a Fractional Output Divider (FOD), and output driver, which together generates a pre-programmed output frequency. Temperature variations of oscillation frequency are continuously monitored by internal precision temperature sensor and provided as input to the frequency control logic block. Using this frequency control logic block, frequency corrections are performed internally for maintaining the output frequency within ±25ppm across temperature range and aging. The output driver is capable of providing both single-ended LVCMOS and differential LVPECL, LVDS, and HCSL output formats. The device contains an internal LDO which reduces the power supply noise, resulting in low noise clock output.

8.3.3 Function Pins

Pin 1 on the LMK6C and pin 1 or pin 2 on the LMK6P, LMK6D, and LMK6H are the function pins which have multiple functions based on the orderable part number. The function can be used as Output Enable (OE), Stand By (ST) or No Connect (NC). Options for both Active High and Active Low are available for OE and ST. Contact TI for Active Low options. Table 8-1 lists the functions of pin 1 and pin 2 for differential output 6-pin packages and Table 8-2 lists the functions of pin 1 for single-ended outputs.



Table 8-1. Function Pin Descriptions for 6-Pin Packages (LMK6D, LMK6H, LMK6P)

ORDERABLE OPTION	PIN DESCRIPTION	OUTPUT FUNCTION	OTHER FUNCTIONAL PIN CONFIGURATION
E (Pin 1)	Output Enable (Active High / NC)	HIGH or No Connect: Output active at Specified Frequency LOW: Output disabled, high impedance; current consumption is given by I _{DD-PD}	Pin 2 can be left floating or grounded
F (Pin 2)	Output Enable (Active High / NC)	HIGH or No Connect: Output active at Specified Frequency LOW: Output disabled, high impedance; current consumption is given by I _{DD-PD}	Pin 1 can be left floating or grounded
A (Pin 1)	Standby (Active Low)	LOW: High Impedance; standby mode; current consumption is given by standby current I _{DD-STBY} HIGH or No Connect: Output active at Specified Frequency	Pin 2 can be left open or grounded
B (Pin 2)	Standby (Active Low)	LOW: High Impedance; standby mode; current consumption is given by standby current I _{DD-STBY} HIGH or No Connect: Output active at Specified Frequency	Pin 1 can be left open or grounded

Table 8-2. Function Pin Descriptions for 4-Pin Packages (LMK6C)

ORDERABLE OPTION	PIN DESCRIPTION	OUTPUT FUNCTION
E (Pin 1)	Output Enable (Active High / NC)	HIGH or No Connect: Output active at Specified Frequency LOW: Output disabled, high impedance; current consumption is given by I _{DD-PD}
A (Pin 1)		LOW : High Impedance; standby mode; current consumption is given by standby current I _{DD-STBY} HIGH or No Connect : Output active at Specified Frequency

In standby mode, all blocks are powered down to provide a maximum current consumption savings equivalent to the standby current provided in the *Current Consumption Characteristics* portion of the *Electrical Characteristics* table. The return to the output clock active time corresponds to same as the initial start-up time.

The Function Pin is driven internally with resistance greater than $100k\Omega$.

8.3.4 Clock Output Interfacing and Termination

These figures show the recommended output interfacing and termination circuits.

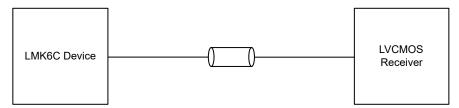


Figure 8-1. LMK6C Output to LVCMOS Receiver

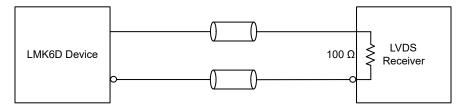


Figure 8-2. LMK6D Output DC-Coupled to LVDS Receiver With Internal Termination/Biasing

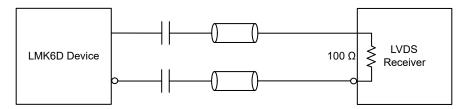


Figure 8-3. LMK6D Output AC Coupled to LVDS Receiver With Internal Termination/Biasing

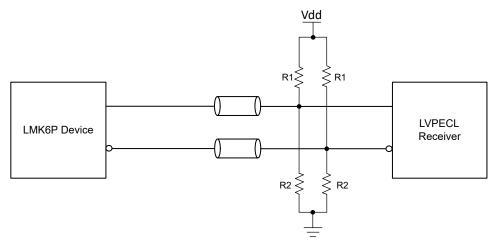


Figure 8-4. LMK6P Output DC-Coupled to LVPECL Receiver With External Termination/Biasing (T-Network)

Table 8-3. LMK6P T-Network DC-Coupled Resistor Values

SUPPLY (V)	R1 (Ω)	R2 (Ω)
3.3	133	82
2.5	250	62.5
1.8	450	56.5



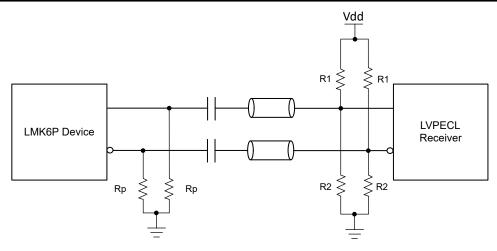


Figure 8-5. LMK6P Output AC-Coupled to LVPECL Receiver With External Termination/Biasing (T-Network)

Table 8-4. LMK6P T-Network AC-Coupled Resistor Values

SUPPLY (V)	Rp (Ω)	R1 (Ω)	R2 (Ω)
3.3	207.5	133	82
2.5	112.5	250	62.5
1.8	83.3	450	56.6

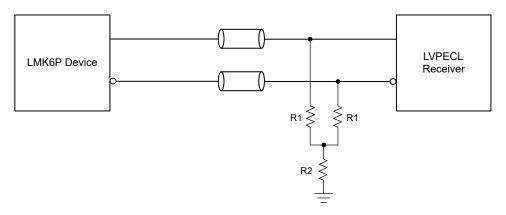


Figure 8-6. LMK6P Output DC-Coupled to LVPECL Receiver With External Termination/Biasing (Y-Network)

Table 8-5. LMK6P Y-Network DC-Coupled Resistor Values

SUPPLY (V)	R1 (Ω)	R2 (Ω)
3.3	50	78.8
2.5	50	31.3
1.8	50	16.7

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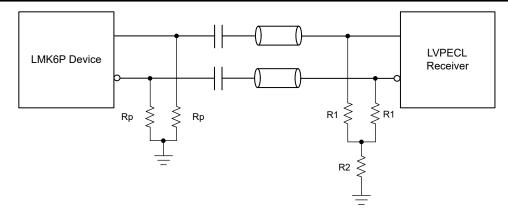


Figure 8-7. LMK6P Output AC-Coupled to LVPECL Receiver With External Termination/Biasing (Y-Network)

Table 8-6. LMK6P Y-Network AC-Coupled Resistor Values

SUPPLY (V)	Rp (Ω)	R1 (Ω)	R2 (Ω)
3.3	207.5	50	78.8
2.5	112.5	50	31.3
1.8	83.3	50	16.7

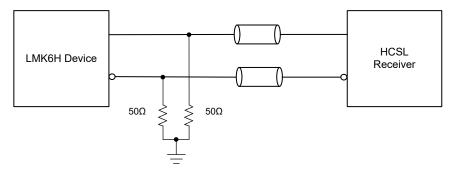


Figure 8-8. LMK6H Output to HCSL Receiver With External Termination

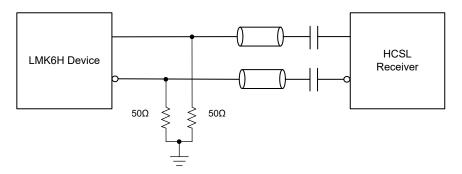


Figure 8-9. LMK6H Output AC-Coupled to HCSL Receiver With External Termination

8.3.5 Temperature Stability

Figure 8-10 shows the frequency variation of the LMK6x differential output oscillator over the temperature range of -40°C to 85°C for total of 60 units. Figure 8-11 shows the frequency variation of the LMK6C single-ended output oscillator over the operating temperature range of -40°C to 105°C. These plots represent the typical temperature stability of the device, remaining below ±10ppm. The devices are soldered onto the evaluation

board as per the standard soldering profile and frequency variation measurements are carried out. The output frequency is 156.25MHz for these tests.

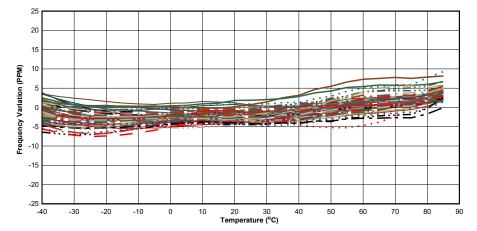


Figure 8-10. Frequency Change Over Temperature (LMK6x Differential Output Device)

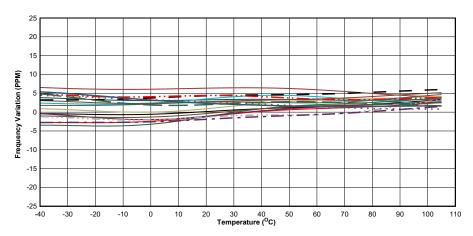


Figure 8-11. Frequency Change Over Temperature (LMK6C Single-Ended Output Device)

8.3.6 Mechanical Robustness

For reference oscillators, vibration and shock are common causes for increased phase noise and jitter, frequency shift and spikes, or even physical damages to the resonator and the package. Compared to quartz crystals, the BAW resonator is more immune to vibration and shock due to the orders of magnitude, smaller mass, and higher frequency, which means force applied to the device from acceleration is much smaller due to smaller mass.

Figure 8-12 shows the LMK6x BAW oscillator vibration performance. In this test, the LMK6x oscillator mounted on an EVM is subject to 10g acceleration force, ranging from 50Hz to 2kHz in x, y, and z-axis. Phase noise trace with spur due to vibration is captured using Keysight® E5052B and frequency deviation is calculated from the spur power. Then the frequency deviation is converted to ppb by noting the carrier frequency and normalized to ppb/g. Finally, the RMS sum of ppb/g along all three axes is reported as the Vibration sensitivity in ppb/g. LMK6x performance under vibration is approximately 2ppb/g while most quartz oscillators best case is 3ppb/g and worse can be above 10ppb/g.

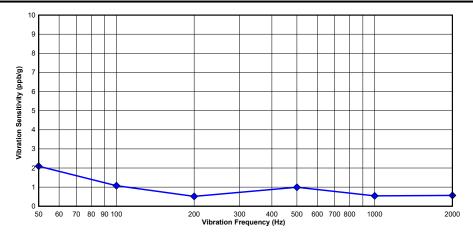


Figure 8-12. LMK6X BAW Oscillator Vibration Performance

8.4 Device Functional Modes

The LMK6x BAW Oscillator is a fixed output frequency device and does not require any programming. The device pin 1 (and pin 2 for a 6-pin device) has different functions. See the *Function Pins* section for more information on the function pins.

9 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

The LMK6x is high-performance, fixed-frequency oscillator that can be used as a reference clock. The product family supports any output frequency between 1MHz to 400MHz for differential LMK6D, LMK6H, LMK6P or 1MHz to 200MHz for singled-ended LVCMOS clock output types, and 1.8V or 2.5V through 3.3V supply rails.

9.2 Typical Application

For reference schematic implementation for LMK6x family of oscillators, refer to the *LMK6EVM User's Guide* for bypass capacitor and AC-coupling capacitor value recommendations. Refer to the *Clock Output Interfacing and Termination* section for output clock required termination and biasing.

Figure 9-1 shows a typical application example. The LMK6D differential oscillator is used as an input to the LVDS buffer input in this example.

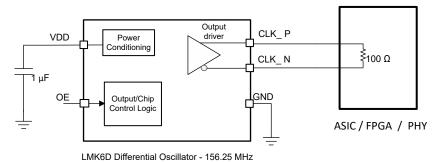


Figure 9-1. Application Example



9.2.1 Design Requirements

The LMK6x is a fixed-frequency oscillator with no programming needed. Make sure to follow the recommended termination options as described in the *Clock Output Interfacing and Termination* section closely. Refer to the *Function Pins* section to understand the pin 1 and pin 2 functions, and order the part number as per the requirements for Output Enable (OE), Standby (ST) options.

9.2.2 Detailed Design Procedure

The LMK6x has three different options for differential output which are LVDS, LVPECL, HCSL type and one LVCMOS single-ended output type. For designing with the any of the oscillator output type in actual system, use the proper AC or DC termination based on the application requirement. Refer to the *Clock Output Interfacing and Termination* section for the details of all the AC and DC termination schemes and use the appropriate option. The figures in this section have all the AC and DC coupling options with the termination resistor values. The LMK6x has an integrated LDO and has excellent PSRR performance as shown in the *Electrical Characteristics* table. Refer to the LMK6EVM for the reference layout recommendation while designing the LMK6x BAW oscillator.

For the Function Pin 1 of LMK6C, connect typical $10k\Omega$ or less resistor to VDD for driving the OE pin High. Note this pin can be left open if using the pullup resistor is undesirable as the device has a greater than $100k\Omega$ internal pullup resistor. For driving the OE pin to Low, use the typical $10k\Omega$ or less resistor as a pulldown resistor. For the Function Pin 1 or Functional Pin 2 for LMK6D, LMK6H, LMK6P, you can use the similar approach described for LMK6C.

9.2.3 Application Curves

The LMK6C LVCMOS output connects to different load capacitances based on the actual application use case in a system. With the different load capacitance, the rise time / fall time varies for the specific output frequency. The following graphs shows the Rise / Fall time for load capacitance of 2.2pF, 4.7pF, 10pF, 15pF and 22pF for temperature range from -40° C to 105° C.

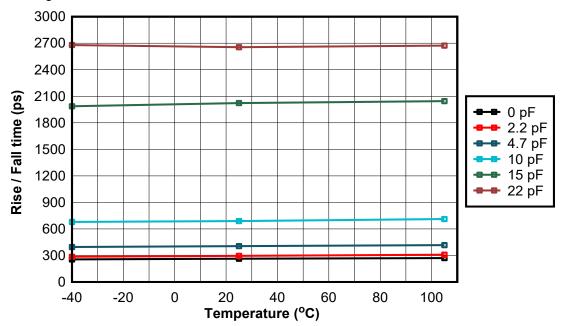


Figure 9-2. Rise / Fall time (ps) vs Temperature for 25MHz Output Frequency, 3.3V Supply



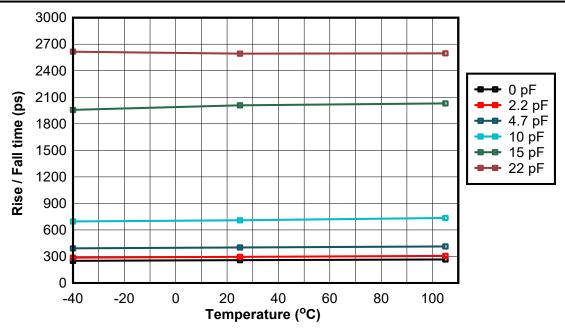


Figure 9-3. Rise / Fall time (ps) vs Temperature for 50MHz Output Frequency, 3.3V Supply

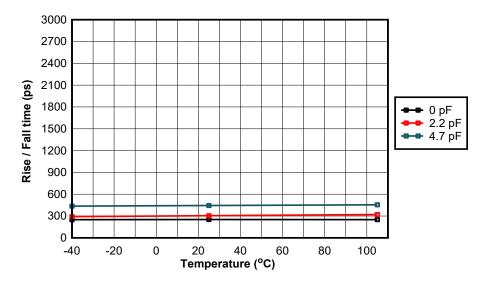


Figure 9-4. Rise / Fall time (ps) vs Temperature for 100MHz Output Frequency, 3.3V Supply



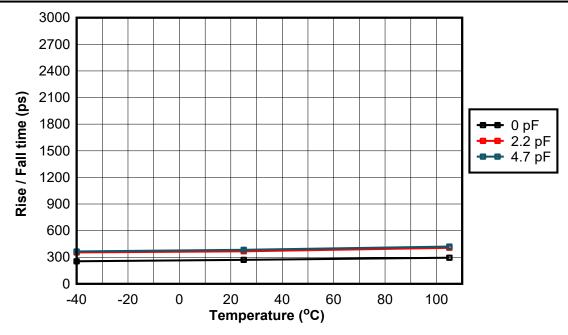


Figure 9-5. Rise / Fall time (ps) vs Temperature for 200MHz Output Frequency, 3.3V Supply

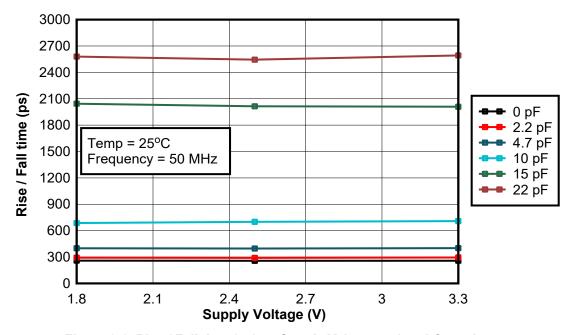


Figure 9-6. Rise / Fall time (ps) vs Supply Voltage vs Load Capacitance

9.3 Power Supply Recommendations

For the best electrical performance of the LMK6x, TI recommends using 1μ F capacitor on the device power supply bypass network. TI also recommends using component side mounting of the power-supply bypass capacitors, and best to use 0201 or 0402 body size capacitors to facilitate signal routing. Keep the connections between the bypass capacitors and the power supply on the device as short as possible. Ground the other side of the capacitor using a low impedance connection to the ground plane.



9.4 Layout

9.4.1 Layout Guidelines

The following sections provide recommendations for board layout, solder reflow profile and power-supply bypassing when using the LMK6x to provide good thermal and electrical performance and signal integrity of the entire system.

9.4.1.1 Providing Thermal Reliability

The LMK6x is a high-performance device. Therefore, pay careful attention to device configuration and printed circuit board (PCB) layout with respect to power consumption. The ground pin must be connected to the ground plane of the PCB through three vias or more to maximize thermal dissipation out of the package.

Equation 1 describes the relationship between the PCB temperature around the LMK6x and the junction temperature.

$$T_{B} = T_{J} - \Psi_{JB} \times P \tag{1}$$

where

- T_B: PCB temperature around the LMK6x
- T_{.I}: Junction temperature of LMK6x
- Ψ_{JB}: Junction-to-board thermal resistance parameter of LMK6x (refer to the *Thermal Information* tables in the Specifications section for this information)
- P: On-chip power dissipation of LMK6x

9.4.1.2 Recommended Solder Reflow Profile

TI recommends following the recommendations provided by the solder paste supplier to optimize flux activity and to achieve proper melting temperatures of the alloy within the guidelines of J-STD-20. Processing the LMK6x with the lowest peak temperature possible is preferable while also remaining below the components peak temperature rating as listed on the MSL label. The exact temperature profile depends on several factors including maximum peak temperature for the component as rated on the MSL label, Board thickness, PCB material type, PCB geometries, component locations, sizes, densities within PCB, as well solder manufactures recommended profile, and capability of the reflow equipment to as confirmed by the SMT assembly operation.



9.4.2 Layout

Refer to the *LMK6EVM User's Guide* for printed circuit board layout examples for LMK6D, LMK6H, LMK6P and LMK6C devices. The figured below show the PCB layout example as done on the evaluation module for the LMK6x EVM.

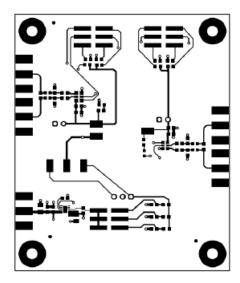


Figure 9-7. PCB Layout Example From LMK6 EVM - Top Layer

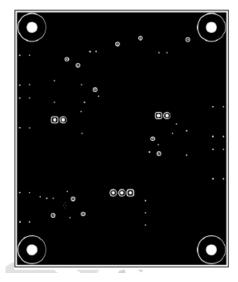


Figure 9-8. PCB Layout Example From LMK6 EVM - GND Layer 1

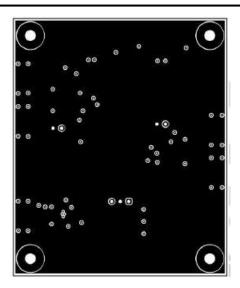


Figure 9-9. PCB Layout Example From LMK6 EVM - GND Layer 2

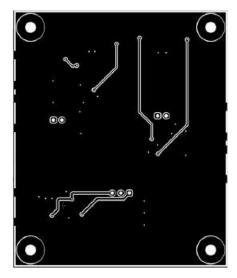


Figure 9-10. PCB Layout Example From LMK6 EVM - Bottom Layer



10 Device and Documentation Support

10.1 Documentation Support

10.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, LMK6EVM User's Guide
- Texas Instruments, Standalone BAW Oscillators Advantages Over Quartz Oscillators, application note
- · Texas Instruments, BAW oscillator solutions for Building Automation, application note
- Texas Instruments, BAW oscillator solutions for Factory Automation, application note
- Texas Instruments, BAW oscillator solutions for Grid Infrastructure, application note
- Texas Instruments, BAW oscillator solutions for Optical Modules, application note

10.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the guick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

10.4 Trademarks

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10.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

10.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

11 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision D (February 2023) to Revision E (January 2024)	Page
Added values to the list of standard frequencies	1
Changed the part number guides in the Device Ordering Information section	3
Changes from Revision C (December 2022) to Revision D (February 2023)	Page
Changed the NO. column to DLE/DLF in the <i>Pin Functions</i> table for the DLF package release.	e5



C	hanges from Revision B (November 2022) to Revision C (December 2022)	Page
•	Changed the data sheet status from Advanced Information to Production Data	1
•	Removed the preview note from the LMK6D, LMK6H, and LMK6P devices	1

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.





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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LMK6CE012288CDLFR	ACTIVE	VSON	DLF	4	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	LCBJ	Samples
LMK6CE012288CDLFT	ACTIVE	VSON	DLF	4	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	LCBJ	Samples
LMK6CE02500CDLFR	ACTIVE	VSON	DLF	4	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	LCBG	Samples
LMK6CE02500CDLFT	ACTIVE	VSON	DLF	4	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	LCBG	Samples
LMK6CE02500DDLFR	ACTIVE	VSON	DLF	4	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	LC1G	Samples
LMK6CE02500DDLFT	ACTIVE	VSON	DLF	4	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	LC1G	Samples
LMK6CE03333CDLER	ACTIVE	VSON	DLE	4	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	HCB8	Samples
LMK6CE03333CDLET	ACTIVE	VSON	DLE	4	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	HCB8	Samples
LMK6CE04000CDLFR	ACTIVE	VSON	DLF	4	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	HCB6	Samples
LMK6CE04000CDLFT	ACTIVE	VSON	DLF	4	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	HCB6	Samples
LMK6CE04800DDLFR	ACTIVE	VSON	DLF	4	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	LC1C	Samples
LMK6CE04800DDLFT	ACTIVE	VSON	DLF	4	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	LC1C	Samples
LMK6CE05000CDLFR	ACTIVE	VSON	DLF	4	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	LCCB	Samples
LMK6CE05000CDLFT	ACTIVE	VSON	DLF	4	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	LCCB	Samples
LMK6CE07425DDLFR	ACTIVE	VSON	DLF	4	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	LC19	Samples
LMK6CE07425DDLFT	ACTIVE	VSON	DLF	4	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	LC19	Samples
LMK6CE10000CDLFR	ACTIVE	VSON	DLF	4	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	LCB8	Samples
LMK6CE10000CDLFT	ACTIVE	VSON	DLF	4	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	LCB8	Samples
LMK6CE10000DDLFR	ACTIVE	VSON	DLF	4	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	LC18	Samples
LMK6CE10000DDLFT	ACTIVE	VSON	DLF	4	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	LC18	Samples





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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LMK6CE12500CDLER	ACTIVE	VSON	DLE	4	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	LCB6	Samples
LMK6CE12500CDLET	ACTIVE	VSON	DLE	4	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	LCB6	Samples
LMK6CE15625DDLFR	ACTIVE	VSON	DLF	4	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	LC12	Samples
LMK6CE15625DDLFT	ACTIVE	VSON	DLF	4	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	LC12	Samples
LMK6DA05184ADLER	ACTIVE	VSON	DLE	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HDAH	Samples
LMK6DA05184ADLET	ACTIVE	VSON	DLE	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HDAH	Samples
LMK6DA10000ADLFR	ACTIVE	VSON	DLF	6	3000	RoHS & Green	Call TI	Level-1-260C-UNLIM	-40 to 85	LDA8	Samples
LMK6DA10000ADLFT	ACTIVE	VSON	DLF	6	250	RoHS & Green	Call TI	Level-1-260C-UNLIM	-40 to 85	LDA8	Samples
LMK6DA12288ADLER	ACTIVE	VSON	DLE	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HDA4	Samples
LMK6DA12288ADLET	ACTIVE	VSON	DLE	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HDA4	Samples
LMK6DA12500ADLFR	ACTIVE	VSON	DLF	6	3000	RoHS & Green	Call TI	Level-1-260C-UNLIM	-40 to 85	LDA6	Samples
LMK6DA12500ADLFT	ACTIVE	VSON	DLF	6	250	RoHS & Green	Call TI	Level-1-260C-UNLIM	-40 to 85	LDA6	Samples
LMK6DA15552ADLER	ACTIVE	VSON	DLE	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HDA3	Samples
LMK6DA15552ADLET	ACTIVE	VSON	DLE	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HDA3	Samples
LMK6DA15625ADLFR	ACTIVE	VSON	DLF	6	3000	RoHS & Green	Call TI	Level-1-260C-UNLIM	-40 to 85	LDA2	Samples
LMK6DA15625ADLFT	ACTIVE	VSON	DLF	6	250	RoHS & Green	Call TI	Level-1-260C-UNLIM	-40 to 85	LDA2	Samples
LMK6DA20000ADLER	ACTIVE	VSON	DLE	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HDA1	Samples
LMK6DA20000ADLET	ACTIVE	VSON	DLE	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HDA1	Samples
LMK6DA31250ADLFR	ACTIVE	VSON	DLF	6	3000	RoHS & Green	Call TI	Level-1-260C-UNLIM	-40 to 85	LDA0	Samples
LMK6DA31250ADLFT	ACTIVE	VSON	DLF	6	250	RoHS & Green	Call TI	Level-1-260C-UNLIM	-40 to 85	LDA0	Samples
LMK6DA40000ADLFR	ACTIVE	VSON	DLF	6	3000	RoHS & Green	Call TI	Level-1-260C-UNLIM	-40 to 85	LDAM	Samples





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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LMK6DA40000ADLFT	ACTIVE	VSON	DLF	6	250	RoHS & Green	Call TI	Level-1-260C-UNLIM	-40 to 85	LDAM	Samples
LMK6HA10000ADLER	ACTIVE	VSON	DLE	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LHA8	Samples
LMK6HA10000ADLET	ACTIVE	VSON	DLE	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LHA8	Samples
LMK6HA10000ADLFR	ACTIVE	VSON	DLF	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LHA8	Samples
LMK6HA10000ADLFT	ACTIVE	VSON	DLF	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LHA8	Samples
LMK6HA10000BDLFR	ACTIVE	VSON	DLF	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LH18	Samples
LMK6HA10000BDLFT	ACTIVE	VSON	DLF	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LH18	Samples
LMK6HA15625ADLER	ACTIVE	VSON	DLE	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LHA2	Samples
LMK6HA15625ADLET	ACTIVE	VSON	DLE	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LHA2	Samples
LMK6HE40000ADLFR	ACTIVE	VSON	DLF	6	3000	RoHS & Green	Call TI	Level-1-260C-UNLIM	-40 to 85	LHGM	Samples
LMK6HE40000ADLFT	ACTIVE	VSON	DLF	6	250	RoHS & Green	Call TI	Level-1-260C-UNLIM	-40 to 85	LHGM	Samples
LMK6PA15625ADLER	ACTIVE	VSON	DLE	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LPA2	Samples
LMK6PA15625ADLET	ACTIVE	VSON	DLE	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LPA2	Samples
LMK6PA15625ADLFR	ACTIVE	VSON	DLF	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LPA2	Samples
LMK6PA15625ADLFT	ACTIVE	VSON	DLF	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LPA2	Samples
PLMK6DA15625ADLET	ACTIVE	VSON	DLE	6	250	TBD	Call TI	Call TI	-40 to 85		Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.



PACKAGE OPTION ADDENDUM

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(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

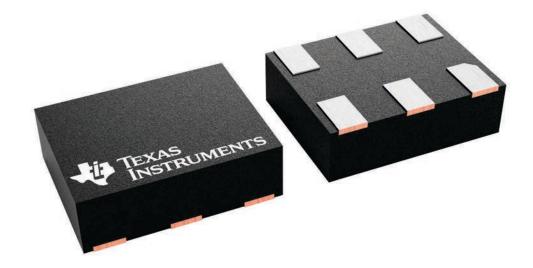
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2.5 x 3.2, multiple pitch

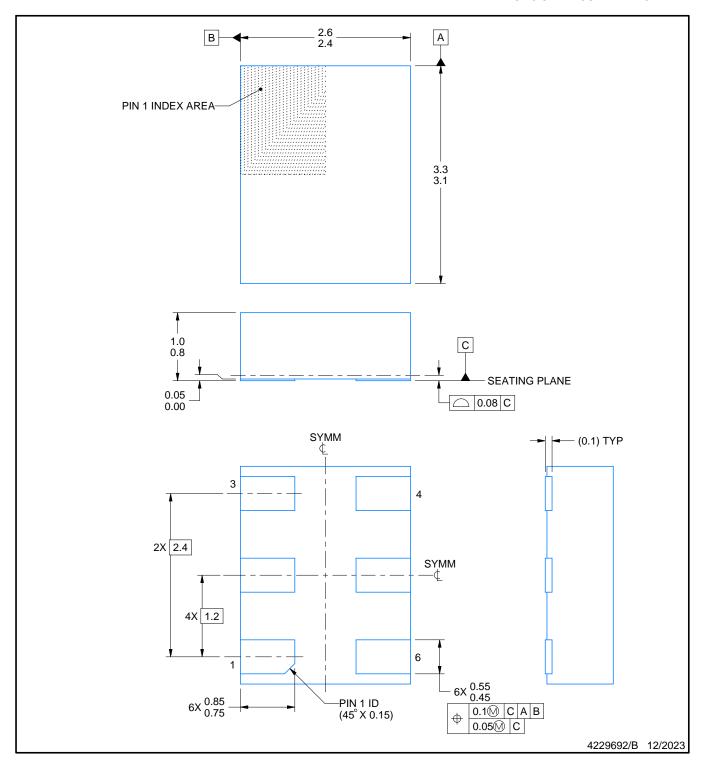
PLASTIC SMALL OUTLINE - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



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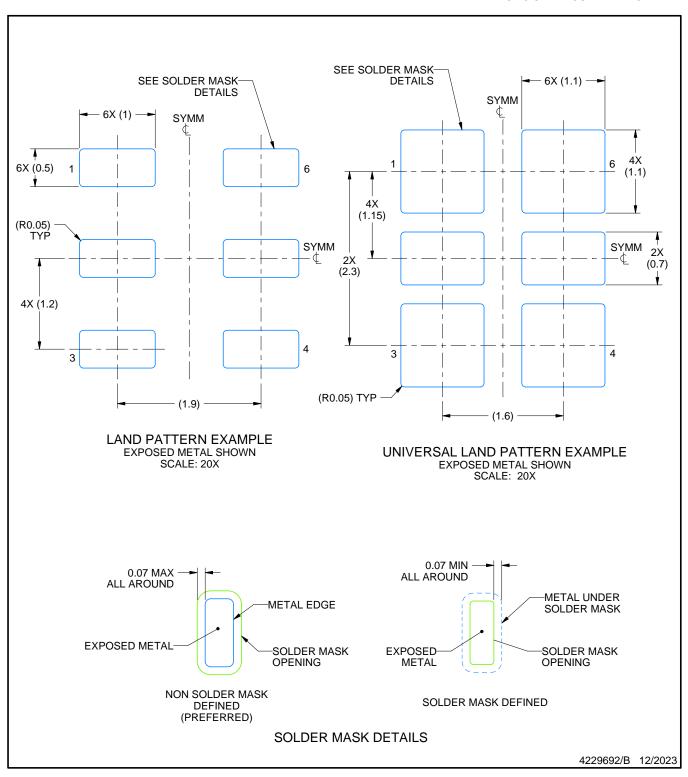




- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

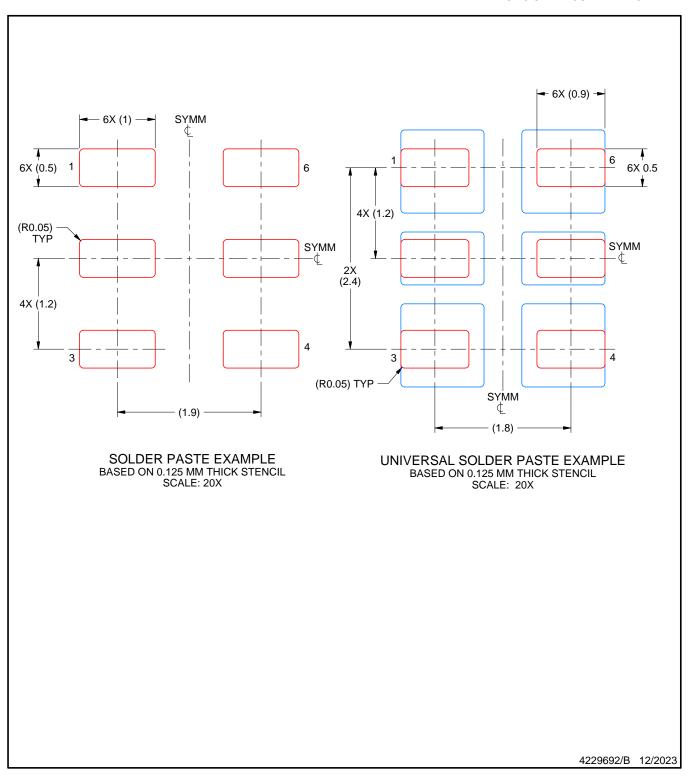




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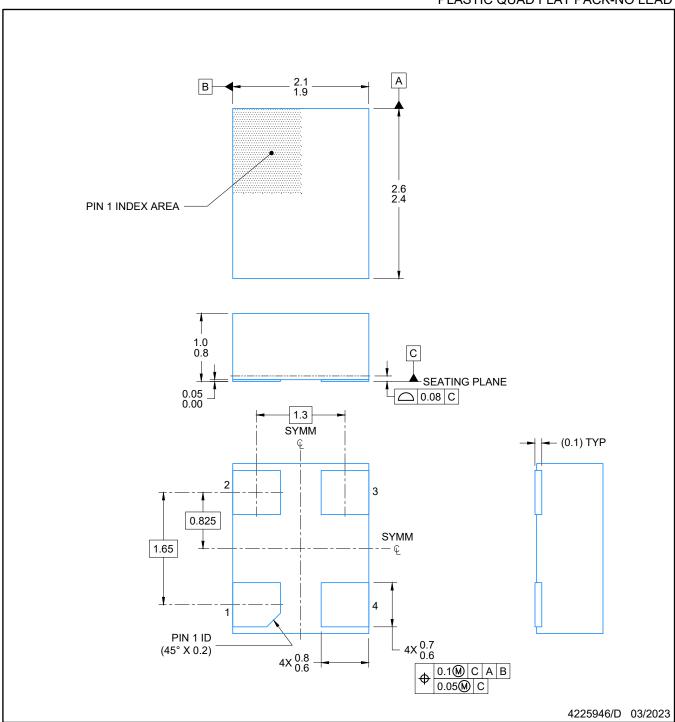
3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).





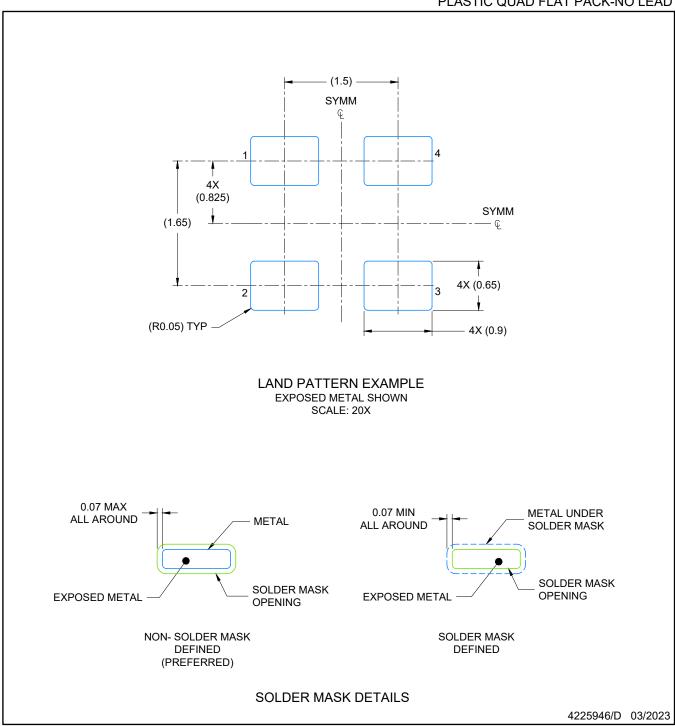
NOTES: (continued)





- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.

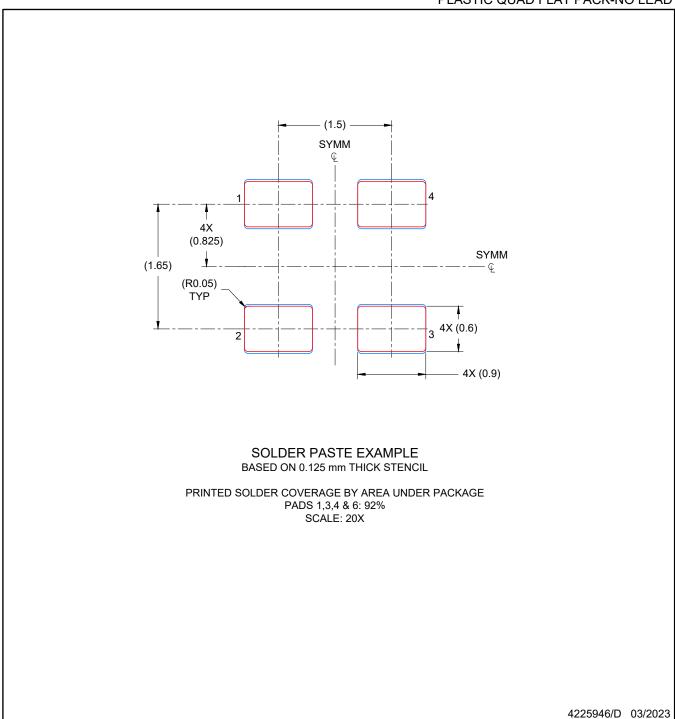




NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).





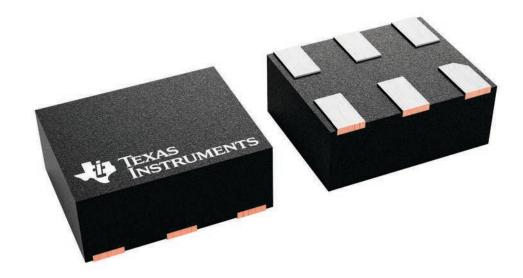
NOTES: (continued)



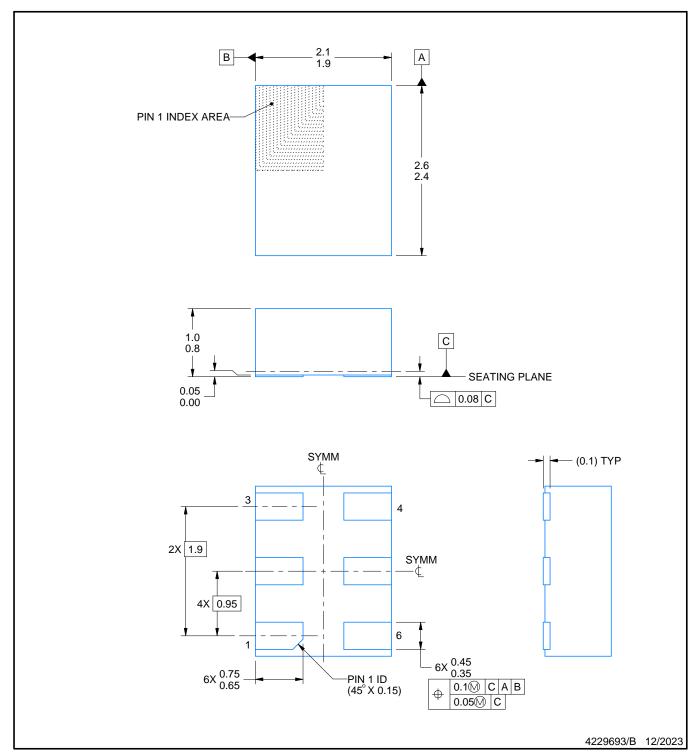
2 x 2.5, multiple pitch

PLASTIC SMALL OUTLINE - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

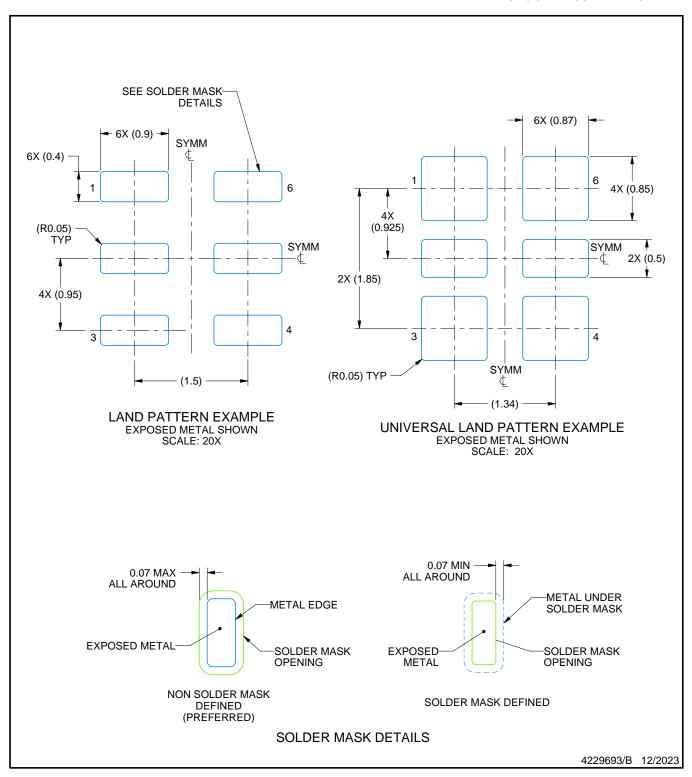






- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.

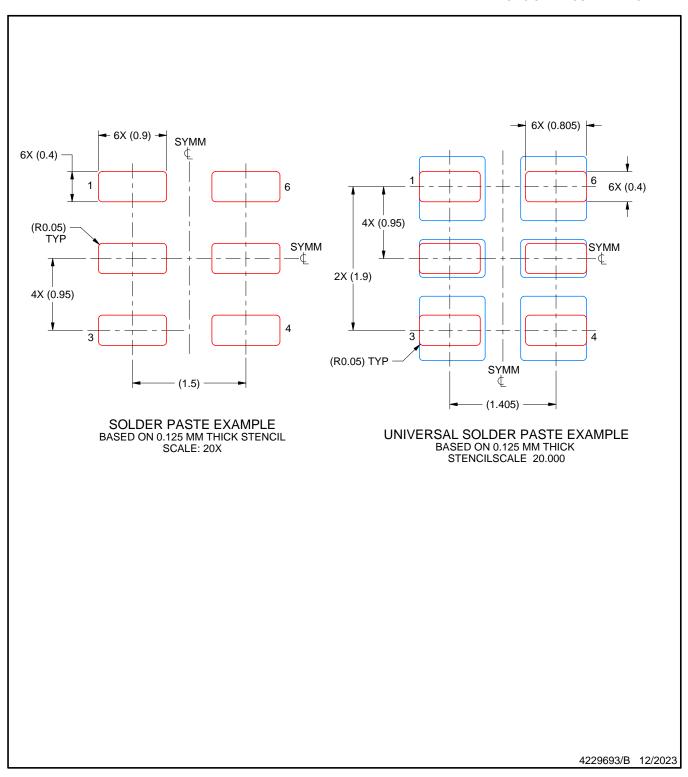




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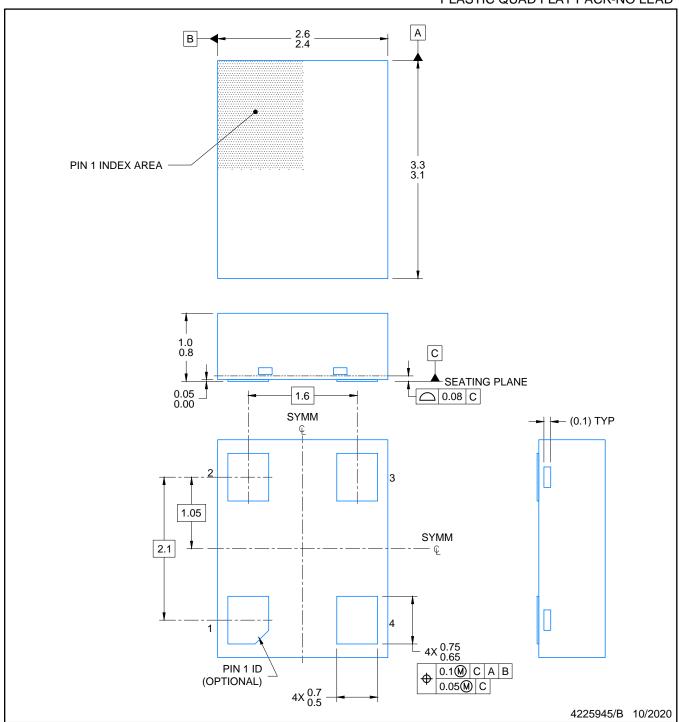
3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).





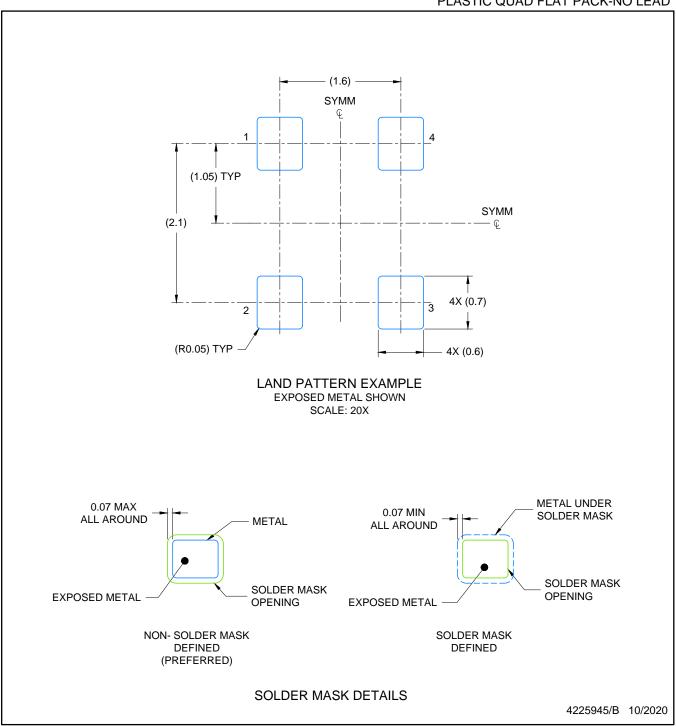
NOTES: (continued)





- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.

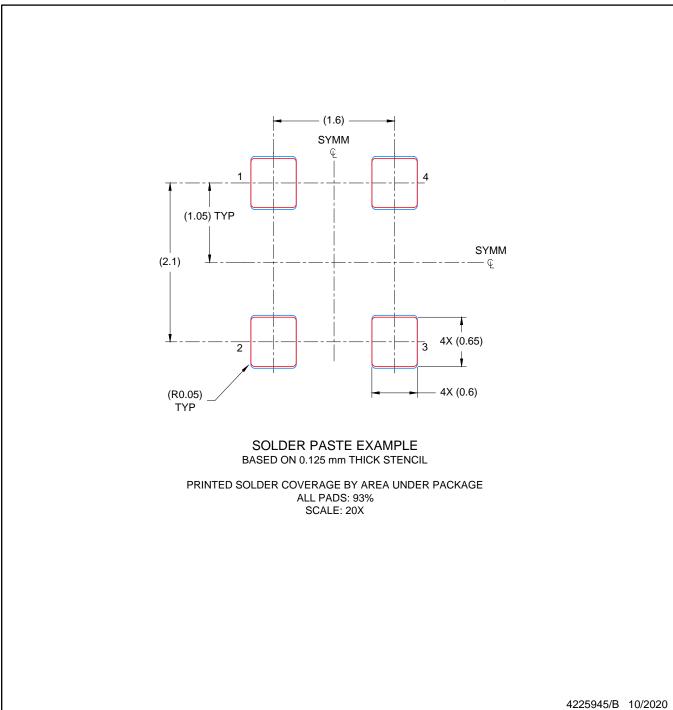




NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271) .





NOTES: (continued)



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